# 1200V 60A N-Channel SiC MOSFET

#### Features

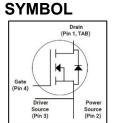
- Low On-Resistance
- Low Capacitance
- Avalanche Ruggedness
- Halogen Free, RoHS Compliant

### BENEFITS

- Higher System Efficiency
- Parallel Device Convenience
- High Temperature Application
- High Frequency Operation

### Application

- Switch Mode Power Supply (SMPS)
- Power Factor Correction (PFC)
- Uninterruptible Power Supply (UPS)
- EV Charging station & Motor Drives
- Solar/ Wind Renewable Energy
- Power Inverters & DC/DC Converters





TO-247-4L

#### ASSEMBLY MESSAGE

Product Name	Package	Packaging
BXW60M1K2J	TO-247-4L	Tube

#### ABSOLUTE MAXIMUM RATINGS (Tc=25°C unless otherwise noted)

Paramot	Parameter		Rating	Unit	
Falanetei		Symbol	TO-247-4L		
Drain-Source Voltage		V <sub>DSS</sub>	1200	V	
Continuous Drain Current	Tc=25°C, VGS=18V	ID	60	A	
Single Pulse Avalanche Energy	L=10mH	Eas	460	mJ	
	L=10mH	las	9.6	A	
Pulsed Drain Current		Ідм	240	A	
Recommend Gate Source Voltage(Static) Maximum Gate Source Voltage(AC (f > 1Hz))		V <sub>GS</sub> ,op	-3/+18	V	
		V <sub>GS,</sub> max	-5/+22	V	
Power Dissipation	Tc=25°C	PD	271.7	W	
Soldering Temperature		TL	260	°C	
Operating Junction and Storage Temperature Range		TJ,TSTG	150,-55~150	°C	
Thermal Resistance, Junction to Case		R <sub>θJC</sub>	0.46	°C / W	



# BXW60M1K2J

#### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub>=25°C, unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS	-					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	VGS=0V, ID=250µA	1200			V
Zero Gate Voltage Drain Current	IDSS	VDS=1200V, VGS=0V			10	uA
Gate-Body Leakage Current, Forward	I <sub>GSS</sub>	VGS=18V,VDS = 0V			250	nA
ON CHARACTERISTICS	•					
Gate Threshold Voltage	V <sub>GS(TH)</sub>	VDS=10V, ID=5mA	1.5		3.0	V
		VGS=20V, ID=30A		36	43	mΩ
rain-Source On-State Resistance	R <sub>DS(ON)</sub>	VGS=18V, ID=30A		40	48	
		VGS=15V, ID=30A		50	60	
		VGS=18V, ID=30A, TJ=150℃		80		
DYNAMIC PARAMETERS						
Input Capacitance	CISS			2400		pF
Output Capacitance	Coss	VDS=1000V,VGS=0V,		120		pF
Reverse Transfer Capacitance	Crss	f=1MHz,VAC=25mV		18		pF
SWITCHING PARAMETERS	•					
Total Gate Charge(Note2)	Q <sub>G</sub>			170		nC
Gate Source Charge	Q <sub>GS</sub>	VDD =800V, VGS =-3/+18 V, ID=30A		10		nC
Gate Drain Charge	Q <sub>GD</sub>			48		nC
Gate plateau voltage	V <sub>pl</sub>			2.6		V
Turn-ON Delay Time	t <sub>D(ON)</sub>			45		ns
Turn-ON Rise Time	t <sub>R</sub>	VDS=800V, ID=30A,		119		ns
Turn-OFF Delay Time	t <sub>D(OFF)</sub>	VGS = -3/+18 V ,RG=25Ω		123		ns
Turn-OFF Fall-Time	t <sub>F</sub>			145		ns
Internal Gate Resistance	R <sub>G(int.)</sub>	f =1MHz, VAC=25mV		2.4		Ω
SOURCE- DRAIN DIODE RATINGS	AND CHA	RACTERISTICS		1	1	1
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	IS=30A, VGS=-3V		4.6		V
Continuous Diode Forward Current	Is	VGS = -3V		60		Α
Reverse Recovery Time	trr	VGS = -3/+18V,IF = 60A,		62		ns
Reverse Recovery Charge	Qrr	VDS=400V,		298		nC
Peak Reverse Recovery Current	I <sub>rrm</sub>	di/dt =500A /µs		10		Α



## BXW60M1K2J

## **TYPICAL CHARACTERISTICS**

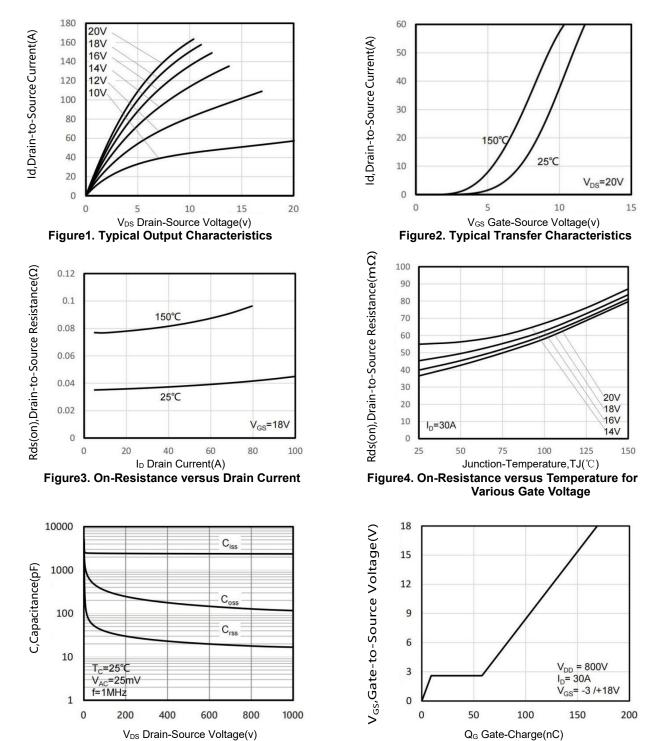


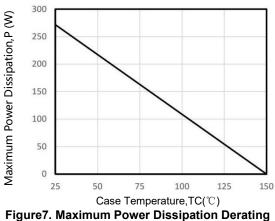
Figure 5. Typical Capacitance versus VDs

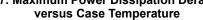
Figure6. Typical Gate Charge versus V<sub>GS</sub>



## BXW60M1K2J

## TYPICAL CHARACTERISTICS(Cont.)





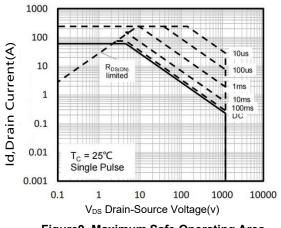


Figure9. Maximum Safe Operating Area

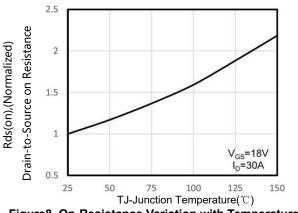


Figure8. On-Resistance Variation with Temperature

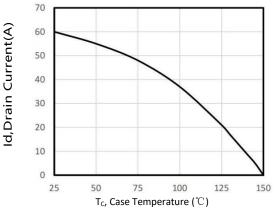
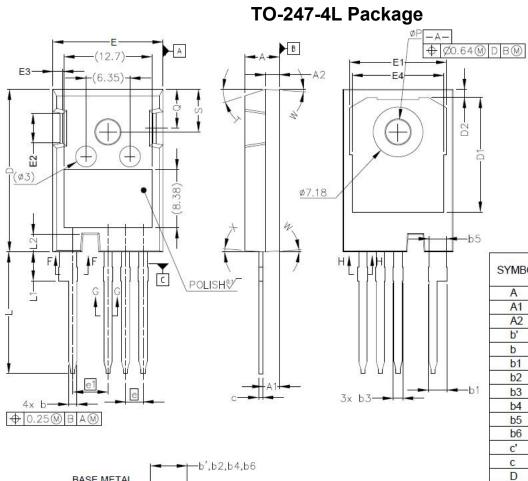
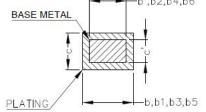


Figure10. Maximum Continuous Drain Current versus Case Temperature



# BXW60M1K2J





SYMBOL	MILLIMETERS		
SYMBOL	MIN	MAX	
A	4.83	5.21	
A1	2.29	2.54	
A2	1.91	2.16	
b'	1.07	1.28	
b	1.07	1.33	
b1	2.39	2.94	
b2	2.39	2.84	
b3	1.07	1.60	
b4	1.07	1.50	
b5	2.39	2.69	
b6	2.39	2.64	
c'	0.55	0.65	
С	0.55	0.68	
D	23.30	23.60	
D1	16.25	17.65	
D2	0.95	1.25	
E	15.75	16.13	
E1	13.10	14.15	
E2	3.68	5.10	
E3	1.00	1.90	
E4	12.38	13.43	
е	2.54	BSC	
e1	5.08 BSC		
N	4		
L	17.31	17.82	
L1	3.97	4.37	
L2	2.35	2.65	
øP Q	3.51	3.65	
	5.49	6.00	
S	6.04	6.30	
Т	17.5° F	REF.	
W	3.5 ° REF. 4° REF.		
Х			



# **Revision history**

# **Document revision history**

Date	Revision	Changes
22-Jan-2022	1.0	First release



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